Product / Process Change Notification

N° 2014-014-A



Dear Customer,

Please find attached our INFINEON Technologies PCN:

ISO1H801G – Design Change

Important information for your attention:

- Please respond to this PCN by indicating your decision on the approval form, sign it and return to your sales partner before 30. June 2014.
- Infineon aligns with the widely-recognized JEDEC STANDARD "JESD46", which stipulates: "Lack of acknowledgement of the PCN within 30 days constitutes acceptance of the change."

Your prompt reply will help Infineon Technologies to assure a smooth and well executed transition. If Infineon does not hear from your side by the due date, we will assume your full acceptance to this proposed change and its implementation.

Your attention and response to this matter is greatly appreciated.

Disclaimer:

If we do not receive any response within the given time limit we consider this as the acceptance of the PCN.

Product / Process Change Notification





SUBJECT OF CHANGE:	Modification of the communication protocol across the galvanic isolation.					
PRODUCTS AFFECTED:	Sales Name ISO1H801G	SP No. SP000722122	OPN ISO1H801GAUMA1	Package PG-DSO-36		
REASON OF CHANGE:	Improve the capability to meet customer's volume demand.					
DESCRIPTION OF CHANGE:	<u>OLD</u>		<u>NEW</u>	NEW		
-	Transceiver wit method for bina	th differential ary data transfer	Transceiver with se transfer of binary va independent chann	Transceiver with separated transfer of binary values on two independent channels		
PRODUCT IDENTIFICATION:	Traceability is ensured by datecode.					
TIME SCHEDULE:						
Final qualification report:	October 2014					
First samples available:	July 2014					
Start of delivery:	From January 2015 onwards					
ASSESSMENT:	No change in fo	orm, fit and functio	n.			
DOCUMENTATION:	2_cip14014_qu	ualification plan				

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Final Qualification Report				Date: 2014-11-18		
Reason for choosing following test vehicle:	Device itse	lf				
Extension of qualification:						
Assessment of Q-Results	Pass					
Reference Products				ISO1H801G		
Test description	Abbr.	Condition	Readout			
Pre-Conditioning J-STD-20-D JESD22 A111	PC			MSL3, 245°C, 3x reflow		
Temperature Cycling JESD22 A104	TC*	Ta min = -55 ℃ Ta max = +150 ℃	0 cyc precon 500 cyc 1000 cyc	0 / 77 0 / 77 0 / 77 0 / 77		
Autoclave JESD22 A102	AC*	Ta = 121°C RH = 100%	0 h precon 96 h	0 / 77 0 / 77 0 / 77		
Temperature Humidity Bias JESD22 A101	THB*	T = 85 °C RH = 85%	0 h precon 168 h 500 h 1000 h	0 / 77 0 / 77 0 / 77 0 / 77 0 / 77		
High Temperature Storage Life JESD22 A-103	HTSL	Ta =150°C	0 h precon 168 h 500 h 1000 h	0 / 77 - 0 / 77 0 / 77 0 / 77		
High Temperature Operating Life JESD22 A108	HTOL	Tj = 150 °C	0 h precon 168 h 500 h 1000 h	0 / 77 - 0 / 77 0 / 77 0 / 77		
ESD Characterization HBM JEDEC22 A114	ESD	НВМ		HBM/2 Withstand Voltage 2500V		
ESD Characterization CDM JEDEC22 C101	ESD	CDM		CDM/Class3 Withstanf Voltage 1500V		
Latch-Up JESD78	LU			Pass		
Electrical Distribution	ED	-40 ℃ +25 ℃ +125 ℃		0 / 30 0 / 30 0 / 30		

* PC is done only for SMD Packages before AC, TC, THB, HAST stress tests

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